

RP104x SERIES

150mA ULTRA LOW SUPPLY CURRENT LDO REGULATOR

NO.EA-150-161026

OUTLINE

The RP104x Series are CMOS-based voltage regulator ICs with high output voltage accuracy, extremely low supply current and low ON-resistance. Each of these ICs consists of a voltage reference unit, an error amplifier, resistor-net for voltage setting, a current limit circuit and a chip enable circuit.

These ICs perform with ultra low supply current (Typ.1.0µA), which prolong the battery life.

Since the packages for these ICs are DFN(PL)1010-4, SOT-23-5 and SC-82AB, therefore high density mounting of the ICs on boards is possible.

FEATURES

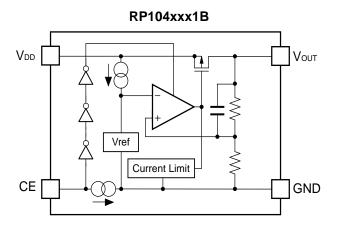
Supply Current	Typ. 1.0μA (Except the current through CE pull down circuit)
Standby Current	
Dropout Voltage	Typ. 0.24V (Iout=150mA, Vout=2.8V)
• Temperature-Drift Coefficient of Output Voltage	
Line Regulation	Typ. 0.02%/V
Output Voltage Accuracy	±0.8%
Packages	DFN(PL)1010-4, SC-82AB, SOT-23-5
Input Voltage Range	1.7V to 5.25V
Output Voltage Range	1.2V to 3.3V (0.1V steps)
	(For other voltages, please refer to MARK INFORMATIONS.)
Built-in Fold Back Protection Circuit	Typ. 40mA (Current at short mode)
Ceramic capacitors are recommended to be used w	ith this IC $0.1 \mu F$ or more

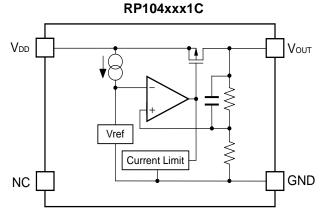
APPLICATIONS

- Power source for portable communication equipment.
- Power source for electrical appliances such as cameras, VCRs and camcorders.
- Power source for battery-powered equipment.

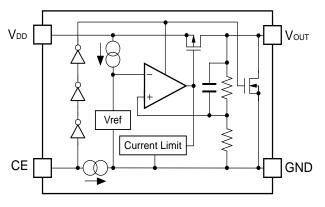
NO.EA-150-161026

BLOCK DIAGRAMS









NO.EA-150-161026

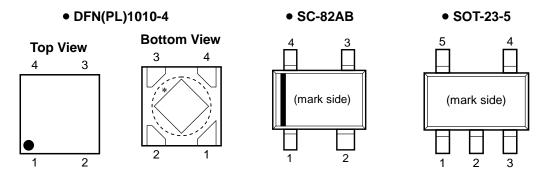
SELECTION GUIDE

The output voltage, chip enable circuit, auto discharge function, package, and the taping type, etc. for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free	
RP104Kxx1*-TR	DFN(PL)1010-4	10,000 pcs	Yes	Yes	
RP104Qxx1*-TR-FE	SC-82AB	3,000 pcs	Yes	Yes	
RP104Nxx1*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes	
2.0V, 2.1V, 2.2V, 2. 3.0V, 3.1V, 3.2V, 3. Exception: 1.85V=F	7V, 1.8V, 1.85V, 1.9V, 3V, 2.4V, 2.5V, 2.6V, 2. 3V	7V, 2.8V, 2.85V, 2.9V,			
 * : CE pin polarity and auto (B) "H" active, without a (C) without chip enable (D) "H" active, with auto 	uto discharge function a circuit, and without auto	at off state o discharge function at of			

NO.EA-150-161026

PIN CONFIGURATIONS



PIN DESCRIPTIONS

• DFN(PL)1010-4

Pin No	Symbol	Pin Description
1	Vout	Output Pin
2	GND	Ground Pin
3	CE / NC	Chip Enable Pin ("H" Active) or No Connection
4	Vdd	Input Pin

*) Tab is GND level. (They are connected to the reverse side of this IC.)

The tab is better to be connected to the GND, but leaving it open is also acceptable.

• SC-82AB

Pin No	Symbol	Pin Description
1	CE / NC	Chip Enable Pin ("H" Active) or No Connection
2	GND	Ground Pin
3	Vout	Output Pin
4	Vdd	Input Pin

• SOT-23-5

Pin No	Symbol	Pin Description
1	Vdd	Input Pin
2	GND	Ground Pin
3	CE / NC	Chip Enable Pin ("H" Active) or No Connection
4	NC	No Connection
5	Vouт	Output Pin

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ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
Vin	Input Voltage	6.0	V
Vce	Input Voltage (CE Pin)	6.0	V
Vout	Output Voltage	-0.3 to VIN+0.3	V
Іоит	Output Current	200	mA
	Power Dissipation (DFN(PL)1010-4)*		
PD	Power Dissipation (SC-82AB)*	380	mW
	Power Dissipation (SOT-23-5)*	420	
Topt	Operating Temperature Range	-40 to 85	°C
Tstg	Storage Temperature Range	-55 to 125	°C

*) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

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ELECTRICAL CHARACTERISTICS

• RP104xxx1B/C/D

 $\label{eq:VineSetVout} V_{\text{IN}} = Set V_{\text{OUT}} + 1V \text{ for Vout options greater than } 1.5V. V_{\text{IN}} = 2.5V \text{ for Vout} \leq 1.5V. \\ I_{\text{OUT}} = 1\text{mA}, C_{\text{IN}} = C_{\text{OUT}} = 0.1 \mu\text{F}, \text{ unless otherwise noted}. \\ \text{The specifications surrounded by} \qquad \text{are guaranteed by Design Engineering at } -40^{\circ}\text{C} \leq T_{\text{OPt}} \leq 85^{\circ}\text{C}. \\ \text{Statistical States} = 0.1 \mu\text{F}, \text{ and } 1.5V. \\ \text{Stat$

		I					Тс	pt=25°C
Symbol	ltem	Conditions			Min.	Тур.	Max.	Unit
		Topt=25°C		×0.992		×1.008	V	
Vout Output Voltage	Output Voltage	Τορι-25 C		$V_{\text{OUT}} \leq 2.0V$	-16		+16	mV
VOUI	Vour Ouiput Voltage	$-40^{\circ}C \le T_{opt} \le 85^{\circ}C$ Vout > 2.0V		×0.985		×1.015	V	
		$-40 \text{ C} \ge 10 \text{ pc}$	≥ 00 C	$V_{\text{OUT}} \leq 2.0V$	-30		+30	mV
Ιουτ	Output Current				150			mA
ΔV out/ ΔI out	Load Regulation	$1mA \le I_{OUT} \le$	150mA			10	20	mV
			1.2V ≤	Vout < 1.5V		0.76	1.05	
			1.5V ≤	Vout < 1.7V		0.53	0.80	
N	Dress suit \/slts s.s	4504	1.7V ≤	1.7V ≤ Vout < 2.0V		0.44	0.65	V
Vdif	Dropout Voltage	Iout=150mA	$2.0V \le V_{\text{OUT}} < 2.5V$			0.34	0.50	
			$2.5V \le V_{\text{OUT}} < 2.8V$			0.28	0.40	
			2.8V ≤	$V_{\text{OUT}} \leq 3.3 V$		0.24	0.32	
lss	Supply Current	Iout=0mA				1.0	1.5	μA
Istandby	Standby Current	Vce=0V				0.1	1.0	μA
ΔV out/ ΔV in	Line Regulation	Set Vout+0.5V \leq VIN \leq 5.0V			0.02	0.10	%/V	
Vin	Input Voltage*				1.7		5.25	V
ΔVουτ/	Output Voltage Temperature Coefficient	-40°C ≤ Topt	≤ 85°C			±40		ppm ∕°C
∆Topt Isc	Short Current Limit					40		mA
		Vout=0V						
PD	CE Pull-down Current					0.3		μA
Vсен	CE Input Voltage "H"				1.5			V
Vcel	CE Input Voltage "L"						0.3	V
RLOW	Low Output Nch Tr. ON Resistance (of D version)	V _{IN} =4.0V V _{CE} =0V				30		Ω

All of units are tested and specified under load conditions such that Tj≈T_{opt}=25°C except for Output Voltage Temperature Coefficient.

*) When Input Voltage is 5.5V, the total operational time must be within 500hrs.

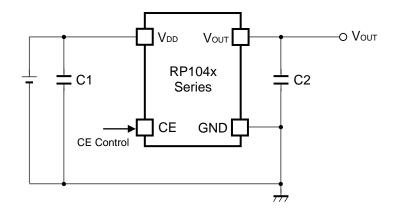
RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

Nisshinbo Micro Devices Inc.

NO.EA-150-161026

TYPICAL APPLICATION



(External Components) C2 0.1μF MURATA: GRM155B31C104KA87B

TECHNICAL NOTES

When using these ICs, consider the following points:

Phase Compensation

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor C2 with good frequency characteristics and ESR (Equivalent Series Resistance). (Note: If additional ceramic capacitors are connected with parallel to the output pin with an output capacitor for phase compensation, the operation might be unstable. Because of this, test these ICs with as same external components as ones to be used on the PCB.)

PCB Layout

Make V_{DD} and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor C1 with a capacitance value as much as 0.1μ F or more between V_{DD} and GND pin, and as close as possible to the pins.

Set external components, especially the output capacitor C2, as close as possible to the ICs, and make wiring as short as possible.

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PACKAGE INFORMATION

Power Dissipation (DFN(PL)1010-4)

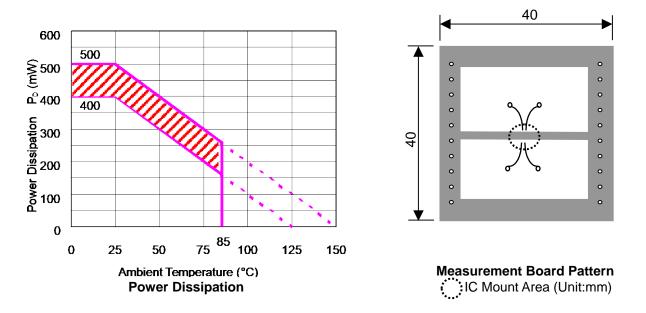
Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below:

Measurement	Conditions
-------------	------------

	Standard Land Pattern	
Environment	Mounting on Board (Wind Velocity=0m/s)	
Board Material	Glass Cloth Epoxy Plastic (Double-sided)	
Board Dimensions	40mm x 40mm x 1.6mm	
Copper Ratio	Topside: Approx. 50%, Backside: Approx. 50%	
Through-holes	φ 0.54mm x 24pcs	

Measurement Result

easurement Result	(Ta=25°C)
	Standard Land Pattern
Power Dissipation	400mW (Tjmax=125°C) 500mW (Tjmax=150°C)
Thermal Resistance	θja = (125-25°C)/0.4W= 250°C/W θjc = 67°C/W

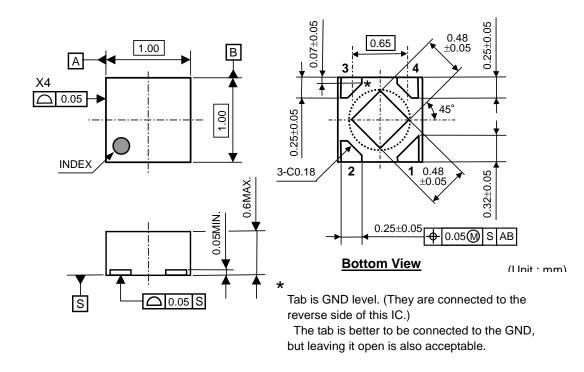


The above graph shows the Power Dissipation of the package based on Tjmax=125°C and Tjmax=150°C. Operating the IC in the shaded area in the graph might have an influence it's lifetime.

Operating time must be within the time limit described in the table below, in case of operating in the shaded area.

Operating Time	Estimated years (Operating 4 hours/day)
13,000 hours	9 years

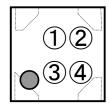
NO.EA-150-161026



• Package Dimensions (DFN(PL)1010-4)

• Mark Specification (DFN(PL)1010-4)

①②: Product Code ... Refer to <u>RP104Kxx1x Series Mark Specification Table</u>
 ③④: Lot No. ... Alphanumeric Serial Number



NO.EA-150-161026

• RP104Kxx1x Series Mark Specification Table (DFN(PL)1010-4)

RP104Kxx1B			RP104Kxx1C			RP104Kxx1D	
Product Name	\mathbb{O}	VSET	Product Name	\bigcirc	VSET	Product Name ①② Vse	T
RP104K121B	AA	1.2V	RP104K121C	BA	1.2V	RP104K121D CA 1.2	V
RP104K131B	AB	1.3V	RP104K131C	BB	1.3V	RP104K131D CB 1.3	V
RP104K151B	AC	1.5V	RP104K151C	BC	1.5V	RP104K151D CC 1.5	V
RP104K181B	AD	1.8V	RP104K181C	BD	1.8V	RP104K181D CD 1.8	V
RP104K191B	AF	1.9V	RP104K191C	BF	1.9V	RP104K191D CF 1.9	V
RP104K201B	AG	2.0V	RP104K201C	BG	2.0V	RP104K201D CG 2.0V	V
RP104K211B	AX	2.1V	RP104K211C	ВX	2.1V	RP104K211D CX 2.1	V
RP104K221B	AU	2.2V	RP104K221C	BU	2.2V	RP104K221D CU 2.2	V
RP104K231B	AV	2.3V	RP104K231C	ΒV	2.3V	RP104K231D CV 2.3	V
RP104K241B	AT	2.4V	RP104K241C	вт	2.4V	RP104K241D CT 2.4	V
RP104K251B	AH	2.5V	RP104K251C	вн	2.5V	RP104K251D CH 2.5	V
RP104K261B	AJ	2.6V	RP104K261C	ВJ	2.6V	RP104K261D CJ 2.6V	V
RP104K271B	AK	2.7V	RP104K271C	BK	2.7V	RP104K271D CK 2.7	V
RP104K281B	AL	2.8V	RP104K281C	BL	2.8V	RP104K281D CL 2.8	V
RP104K291B	AN	2.9V	RP104K291C	BN	2.9V	RP104K291D CN 2.9	V
RP104K301B	AP	3.0V	RP104K301C	BP	3.0V	RP104K301D CP 3.0	V
RP104K311B	AS	3.1V	RP104K311C	BS	3.1V	RP104K311D CS 3.1	V
RP104K321B	AQ	3.2V	RP104K321C	BQ	3.2V	RP104K321D CQ 3.2	V
RP104K331B	AR	3.3V	RP104K331C	BR	3.3V	RP104K331D CR 3.3	V
RP104K181B5	AE	1.85V	RP104K181C5	BE	1.85V	RP104K181D5 CE 1.85	5V
RP104K281B5	AM	2.85V	RP104K281C5	BM	2.85V	RP104K281D5 CM 2.85	5V
RP104K171B	AY	1.7V	RP104K171C	ΒY	1.7V	RP104K171D CY 1.7	V

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• Power Dissipation (SC-82AB)

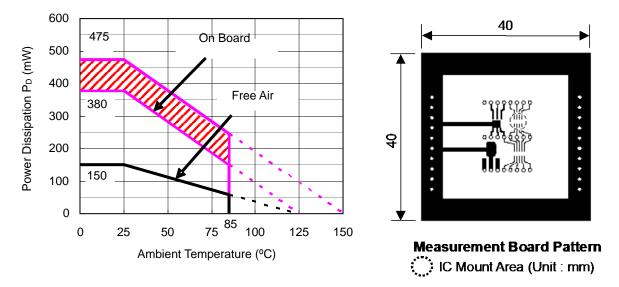
Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below:

Measurement Conditions

	Standard Land Pattern				
Environment Mounting on Board (Wind Velocity=0m/s)					
Board Material Glass Cloth Epoxy Plastic (Double-sided)					
Board Dimensions 40mm × 40mm × 1.6mm					
Copper Ratio	Topside: Approx. 50%, Backside: Approx. 50%				
Through-hole					

Measurement Result

Measurement Result (T						
	Standard Land Pattern	Free Air				
Power Dissipation	380mW (Tjmax=125°C) 475mW (Tjmax=150°C)	150mW (Tjmax=125ºC)				
Thermal Resistance	θja=(125-25°C)/0.38W=263°C/W	667°C/W				



Power Dissipation

The above graph shows the Power Dissipation of the package based on Tjmax=125°C and Tjmax=150°C. Operating the IC in the shaded area in the graph might have an influence it's lifetime.

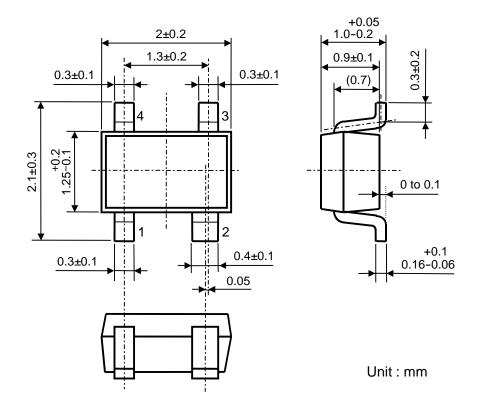
Operating time must be within the time limit described in the table below, in case of operating in the shaded area.

Operating Time	Estimated years (Operating 4 hours/day)				
9,000 hours	6 years				

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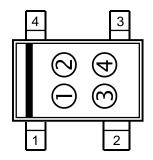
NO.EA-150-161026

• Package Dimensions (SC-82AB)



• Mark Specification (SC-82AB)

①②: Product Code ... Refer to <u>RP104Qxx1x Series Mark Specification Table</u>
 ③④: Lot No. ... Alphanumeric Serial Number



NO.EA-150-161026

• RP104Qxx1xSeries Mark Specification Table (SC-82AB)

RP104Qxx1B

Product Name	12	VSET					
RP104Q121B	L0	1.2V					
RP104Q131B	L1	1.3V					
RP104Q151B	L2	1.5V					
RP104Q181B	L3	1.8V					
RP104Q191B	L5	1.9V					
RP104Q201B	L6	2.0V					
RP104Q211B	T1	2.1V					
RP104Q221B	M8	2.2V					
RP104Q231B	M9	2.3V					
RP104Q241B	Μ7	2.4V					
RP104Q251B	L7	2.5V					
RP104Q261B	L8	2.6V					
RP104Q271B	L9	2.7V					
RP104Q281B	M0	2.8V					
RP104Q291B	M2	2.9V					
RP104Q301B	М3	3.0V					
RP104Q311B	M6	3.1V					
RP104Q321B	M4	3.2V					
RP104Q331B	M5	3.3V					
RP104Q181B5	L4	1.85V					
RP104Q281B5	M 1	2.85V					

RP104Qxx1C		
Product Name	10	VSET
RP104Q121C	NO	1.2V
RP104Q131C	N1	1.3V
RP104Q151C	N2	1.5V
RP104Q181C	N3	1.8V
RP104Q191C	N5	1.9V
RP104Q201C	N6	2.0V
RP104Q211C	U1	2.1V
RP104Q221C	P8	2.2V
RP104Q231C	P9	2.3V
RP104Q241C	P7	2.4V
RP104Q251C	N7	2.5V
RP104Q261C	N8	2.6V
RP104Q271C	N9	2.7V
RP104Q281C	P0	2.8V
RP104Q291C	P2	2.9V
RP104Q301C	P3	3.0V
RP104Q311C	P6	3.1V
RP104Q321C	P4	3.2V
RP104Q331C	P5	3.3V
RP104Q181C5	N4	1.85V
RP104Q281C5	P1	2.85V

RP104Qxx1D		
Product Name	12	VSET
RP104Q121D	R0	1.2V
RP104Q131D	R1	1.3V
RP104Q151D	R2	1.5V
RP104Q181D	R3	1.8V
RP104Q191D	R5	1.9V
RP104Q201D	R6	2.0V
RP104Q211D	V1	2.1V
RP104Q221D	S8	2.2V
RP104Q231D	S9	2.3V
RP104Q241D	S7	2.4V
RP104Q251D	R7	2.5V
RP104Q261D	R8	2.6V
RP104Q271D	R9	2.7V
RP104Q281D	S 0	2.8V
RP104Q291D	S2	2.9V
RP104Q301D	S3	3.0V
RP104Q311D	S 6	3.1V
RP104Q321D	S4	3.2V
RP104Q331D	S 5	3.3V
RP104Q181D5	R4	1.85V
RP104Q281D5	S1	2.85V

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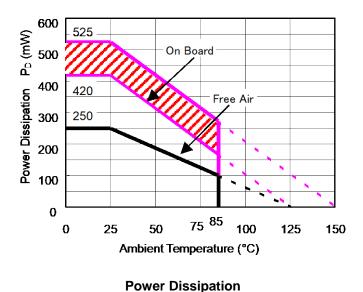
• Power Dissipation (SOT-23-5)

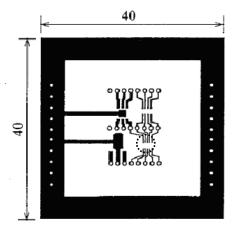
Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below. (Power Dissipation (SOT-23-5) is substitution of SOT-23-6.)

Measurement Conditions

	Standard Land Pattern			
Environment	Mounting on Board (Wind Velocity=0m/s)			
Board Material	Glass Cloth Epoxy Plastic (Double-sided)			
Board Dimensions 40mm x 40mm x 1.6mm				
Copper Ratio	Topside: Approx. 50%, Backside: Approx. 50%			
Through-holes	Through-holes			

M	easurement Result		(Ta=25°C)
		Standard Land Pattern	Free Air
	Power Dissipation	420mW (Tjmax=125°C) 525mW (Tjmax=150°C)	250mW (Tjmax=125°C)
	Thermal Resistance	θja = (125-25°C)/0.42W= 238°C/W	400°C/W







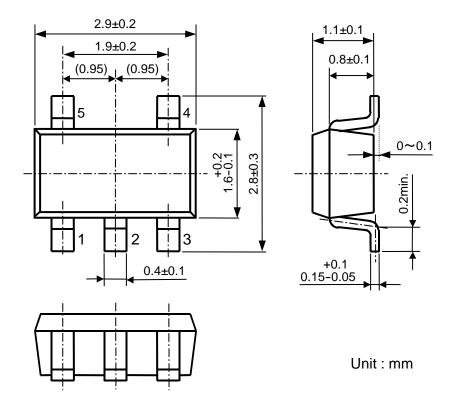
The above graph shows the Power Dissipation of the package based on Tjmax=125°C and Tjmax=150°C. Operating the IC in the shaded area in the graph might have an influence it's lifetime.

Operating time must be within the time limit described in the table below, in case of operating in the shaded area.

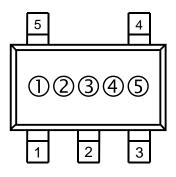
Operating Time	Estimated years (Operating 4 hours/day)
9,000 hours	6 years

NO.EA-150-161026

• Package Dimensions (SOT-23-5)



- Mark Specification (SOT-23-5)
 - ①②③: Product Code ... Refer to <u>RP104Nxx1x Series Mark Specification Table</u>
 ④⑤: Lot No. ... Alphanumeric Serial Number



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• RP104Nxx1x Series Mark Specification Table (SOT-23-5)

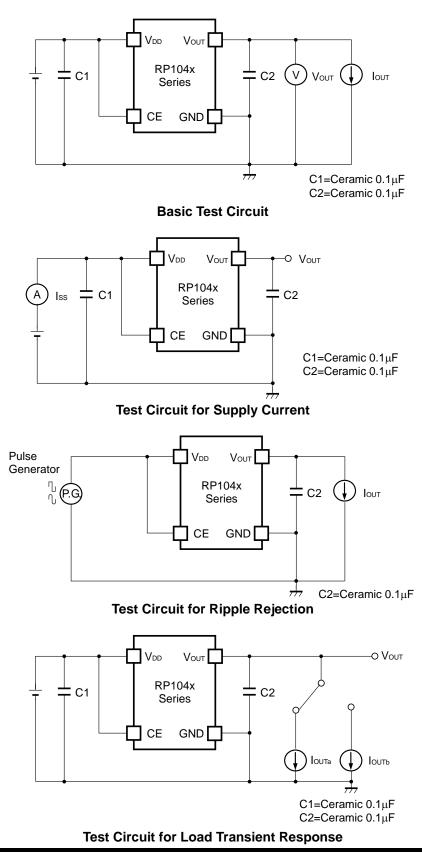
RP104Nxx1B

RP104Nxx1B			RP104Nxx1C				RP104Nxx1D			
Product Name	123	VSET	Product Name	023	VSET		Product Name	123	VSET	
RP104N121B	90A	1.2V	RP104N121C	91A	1.2V		RP104N121D	92A	1.2V	
RP104N131B	90B	1.3V	RP104N131C	91B	1.3V		RP104N131D	92B	1.3V	
RP104N151B	90C	1.5V	RP104N151C	91C	1.5V		RP104N151D	92C	1.5V	
RP104N181B	90D	1.8V	RP104N181C	91D	1.8V		RP104N181D	92D	1.8V	
RP104N191B	90F	1.9V	RP104N191C	91F	1.9V		RP104N191D	92F	1.9V	
RP104N201B	90G	2.0V	RP104N201C	91G	2.0V		RP104N201D	92G	2.0V	
RP104N211B	90X	2.1V	RP104N211C	91X	2.1V		RP104N211D	92X	2.1V	
RP104N221B	90U	2.2V	RP104N221C	91U	2.2V		RP104N221D	92U	2.2V	
RP104N231B	90V	2.3V	RP104N231C	91V	2.3V		RP104N231D	92V	2.3V	
RP104N241B	90T	2.4V	RP104N241C	91T	2.4V		RP104N241D	92T	2.4V	
RP104N251B	90H	2.5V	RP104N251C	91H	2.5V		RP104N251D	92H	2.5V	
RP104N261B	90J	2.6V	RP104N261C	91J	2.6V		RP104N261D	92J	2.6V	
RP104N271B	90K	2.7V	RP104N271C	91K	2.7V		RP104N271D	92K	2.7V	
RP104N281B	90L	2.8V	RP104N281C	91L	2.8V		RP104N281D	92L	2.8V	
RP104N291B	90N	2.9V	RP104N291C	91N	2.9V		RP104N291D	92N	2.9V	
RP104N301B	90P	3.0V	RP104N301C	91P	3.0V		RP104N301D	92P	3.0V	
RP104N311B	90S	3.1V	RP104N311C	91S	3.1V		RP104N311D	92S	3.1V	
RP104N321B	90Q	3.2V	RP104N321C	91Q	3.2V		RP104N321D	92Q	3.2V	
RP104N331B	90R	3.3V	RP104N331C	91R	3.3V		RP104N331D	92R	3.3V	
RP104N181B5	90E	1.85V	RP104N181C5	91E	1.85V		RP104N181D5	92E	1.85V	
RP104N281B5	90M	2.85V	RP104N281C5	91M	2.85V		RP104N281D5	92M	2.85V	
RP104N171B	90Y	1.7V	RP104N171C	91Y	1.7V		RP104N171D	92Y	1.7V	

<u>RP</u>104x

NO.EA-150-161026

TEST CIRCUITS

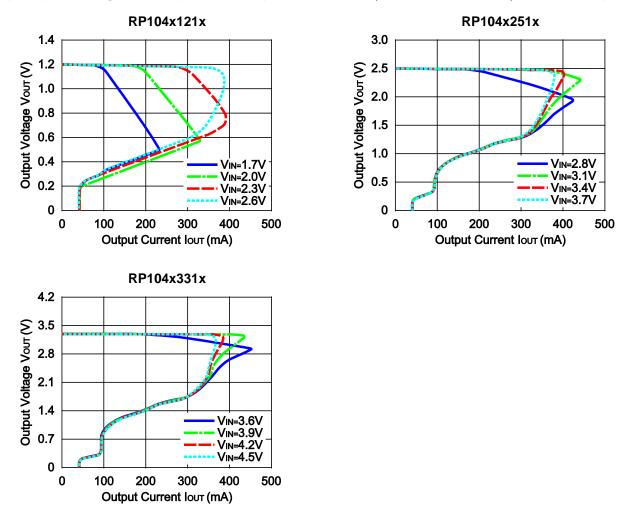


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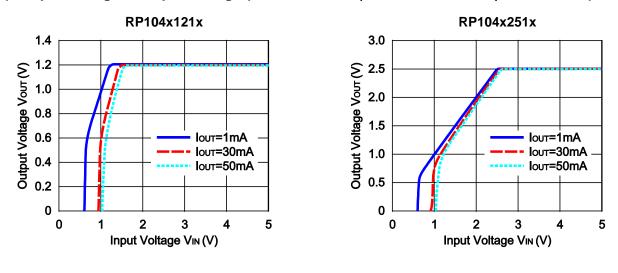
NO.EA-150-161026

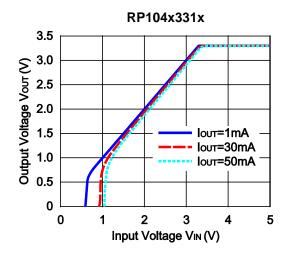
TYPICAL CHARACTERISTICS

1) Output Voltage vs. Output Current (C1=Ceramic 0.1µF, C2=Ceramic 0.1µF, Topt=25°C)

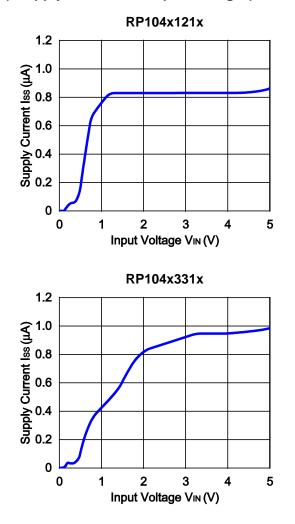


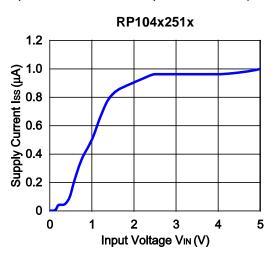
2) Output Voltage vs. Input Voltage (C1=Ceramic 0.1µF, C2=Ceramic 0.1µF, Topt=25°C)



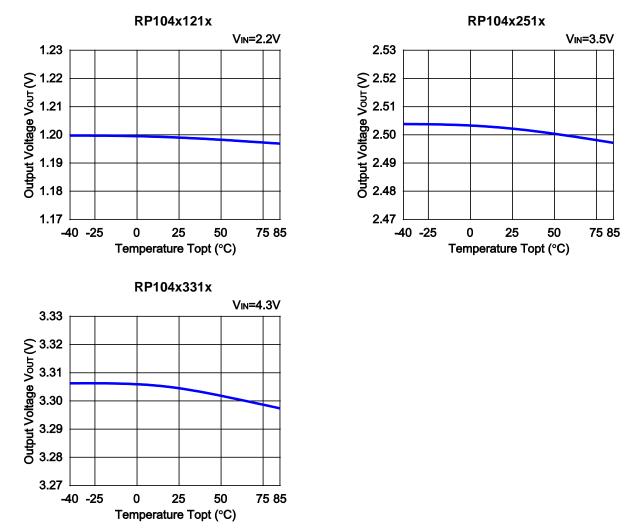


3) Supply Current vs. Input Voltage (C1=Ceramic 0.1µF, C2=Ceramic 0.1µF, Topt=25°C)



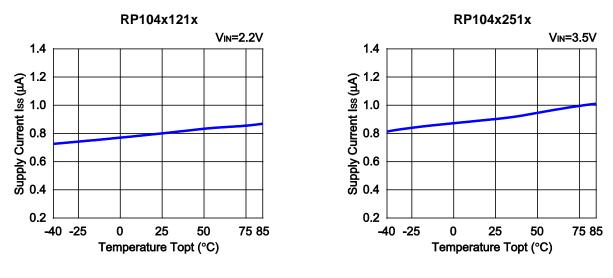


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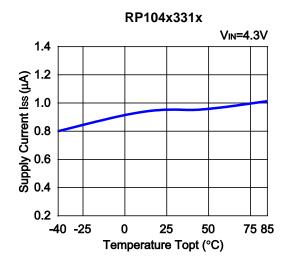


4) Output Voltage vs. Temperature (C1=Ceramic 0.1µF, C2=Ceramic 0.1µF, Iout=1mA)

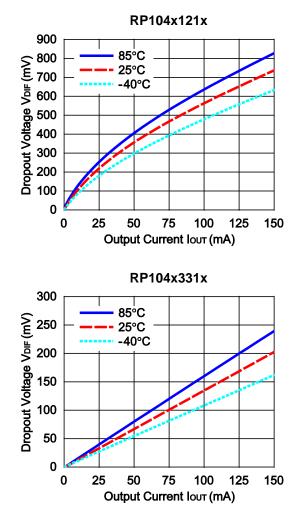
5) Supply Current vs. Temperature (C1=Ceramic 0.1 μ F, C2=Ceramic 0.1 μ F)

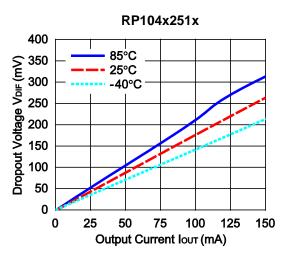


NO.EA-150-161026

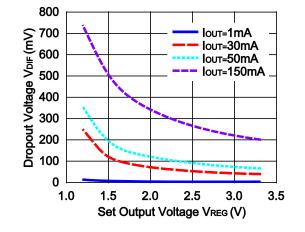


6) Dropout Voltage vs. Output Current (C1=Ceramic 0.1µF, C2=Ceramic 0.1µF, Topt=25°C)

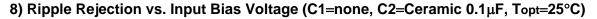


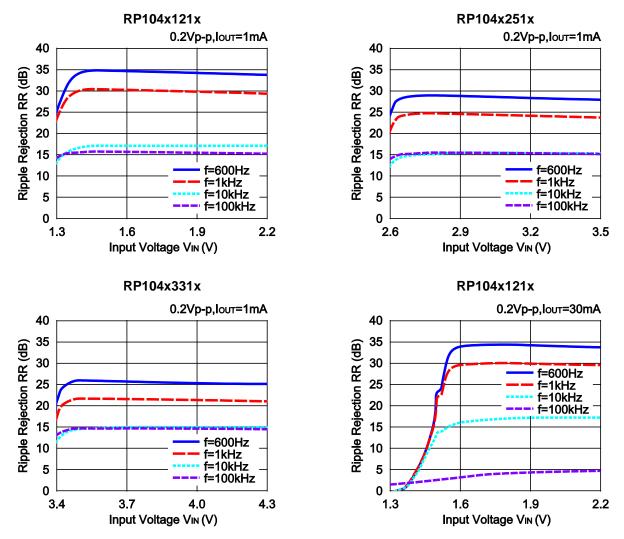


NO.EA-150-161026



7) Dropout Voltage vs. Set Output Voltage (C1=Ceramic 0.1µF, C2=Ceramic 0.1µF, Topt=25°C)

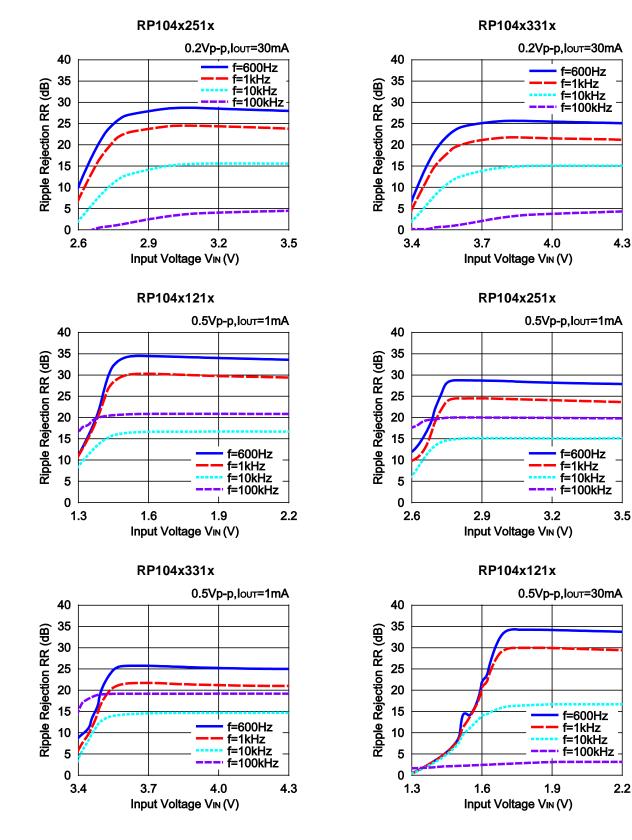




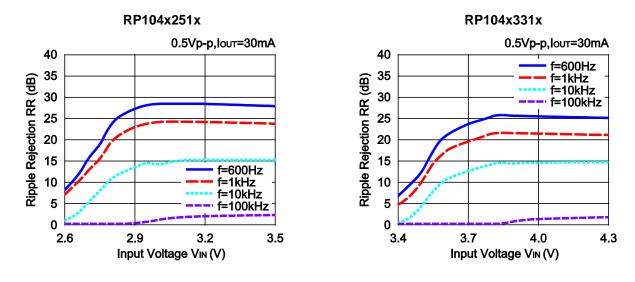
*RP104Q (SC-82AB) is the discontinued product. As of March in 2018

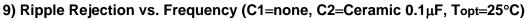
RP104x

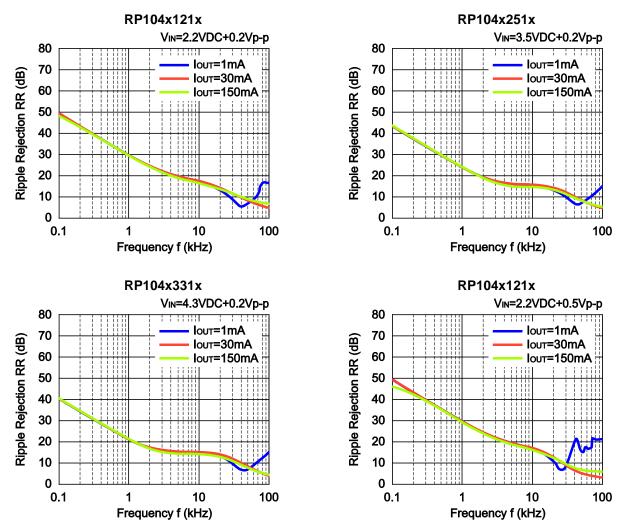
NO.EA-150-161026



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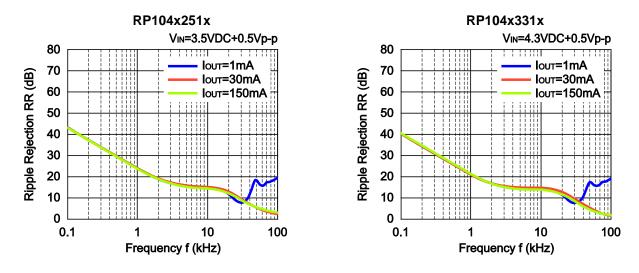


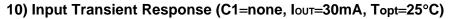


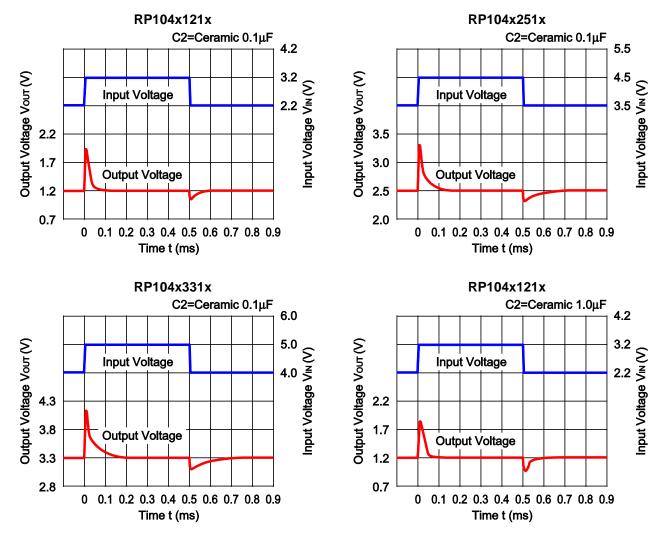


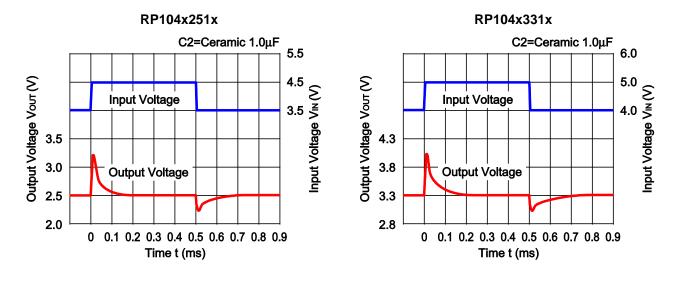
*RP104Q (SC-82AB) is the discontinued product. As of March in 2018

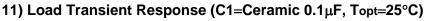
<u>RP104x</u>

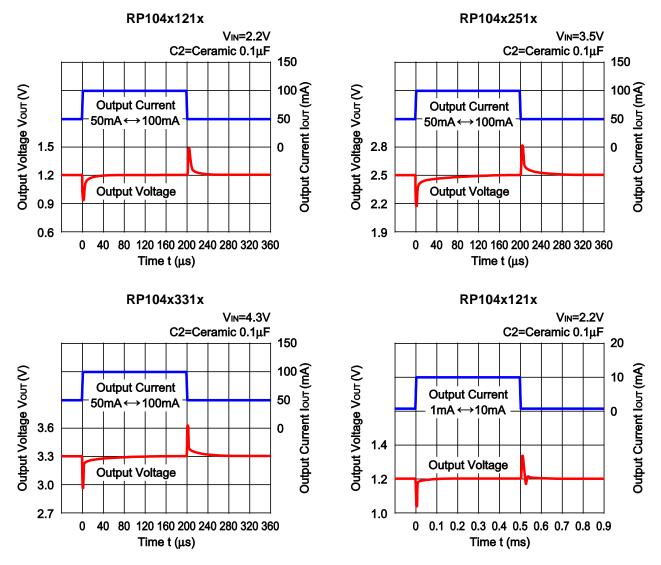






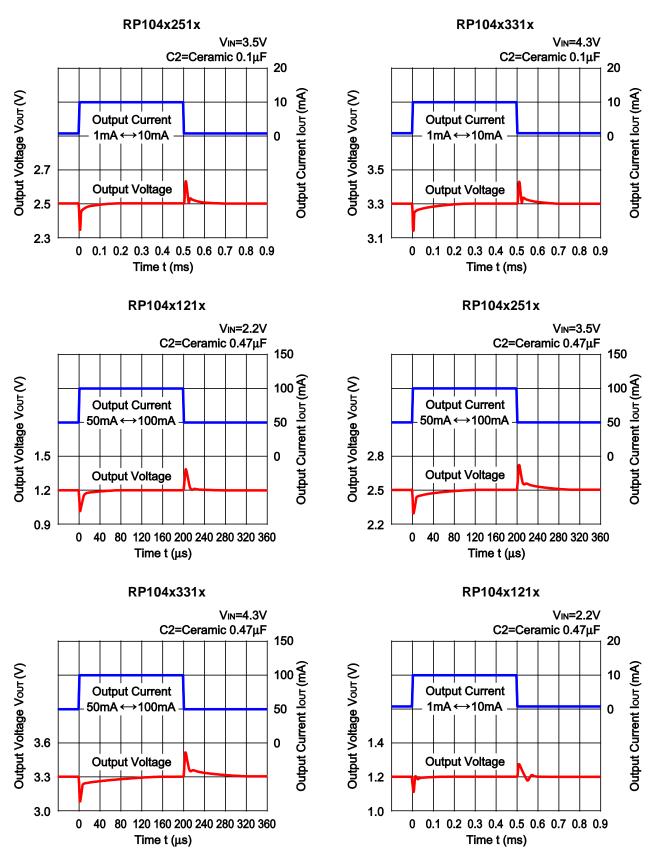




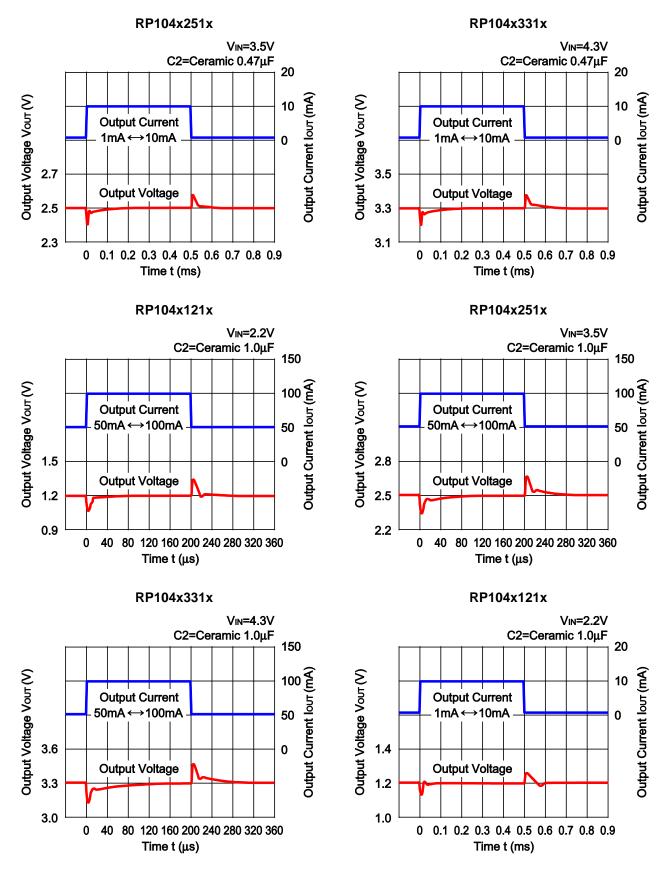


*RP104Q (SC-82AB) is the discontinued product. As of March in 2018

RP104x



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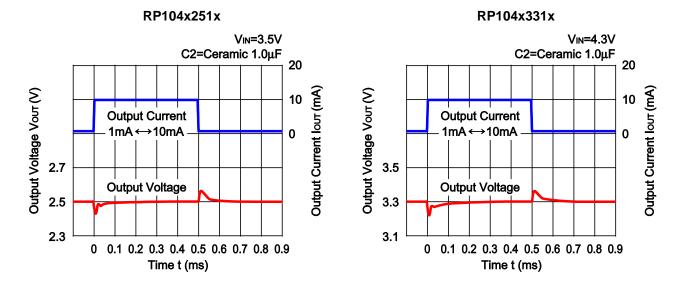


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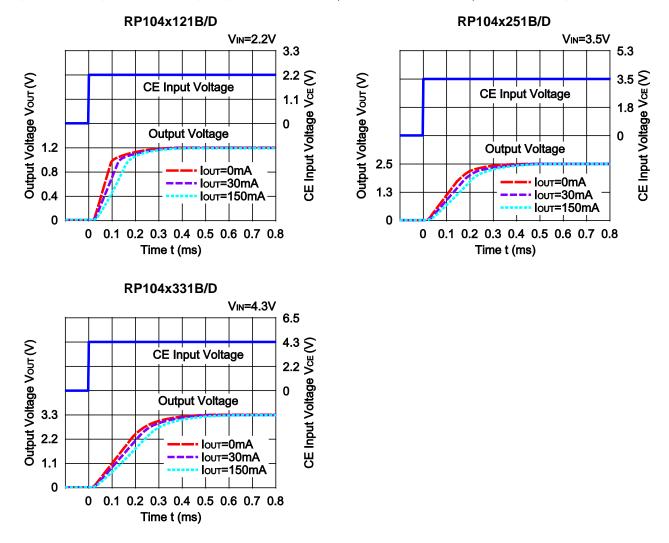
*RP104Q (SC-82AB) is the discontinued product. As of March in 2018

RP104x

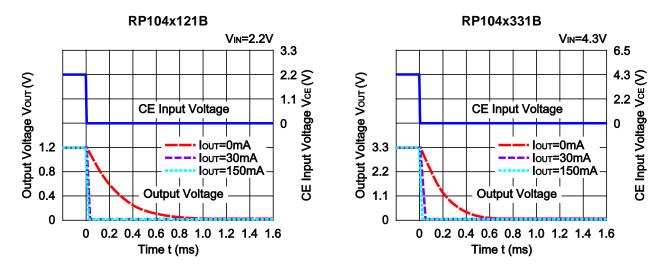
NO.EA-150-161026



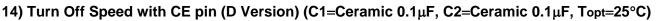
12) Turn On Speed with CE pin (C1=Ceramic 0.1µF, C2=Ceramic 0.1µF, Topt=25°C)

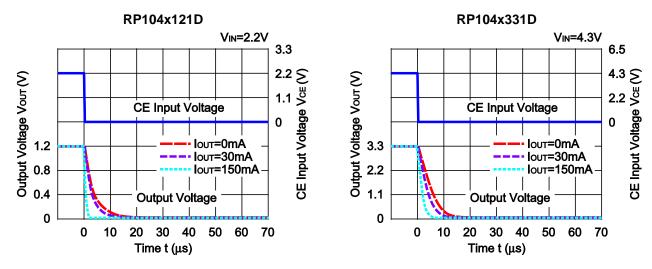


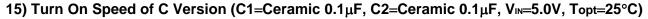
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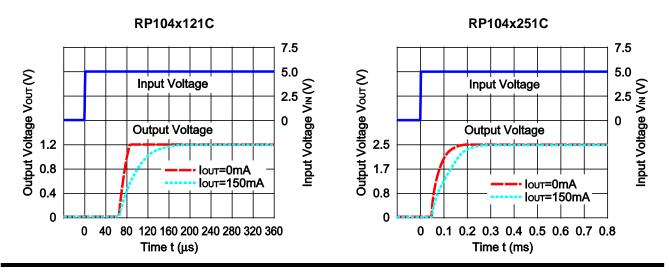


13) Turn Off Speed with CE pin (B Version) (C1=Ceramic 0.1µF, C2=Ceramic 0.1µF, Topt=25°C)



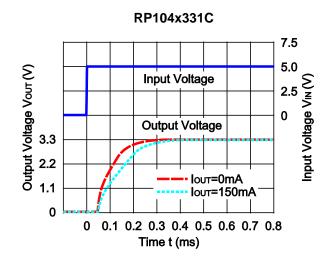






*RP104Q (SC-82AB) is the discontinued product. As of March in 2018

RP104x



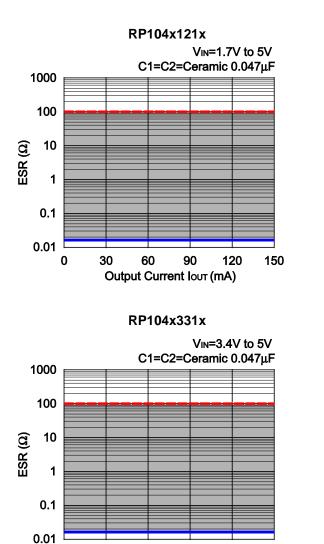
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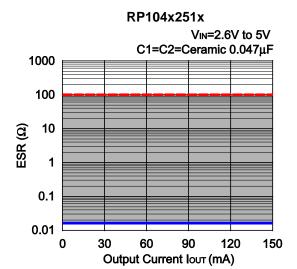
ESR vs. Output Current

Ceramic type output capacitor is recommended for this series; however, the other output capacitors with low ESR also can be used. The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below. The conditions when the white noise level is under $40\mu V$ (Avg.) are marked as the hatched area in the graph.

Measurement conditions

Frequency Band : 10Hz to 2MHz Temperature : -40°C to 85°C





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0

30

60

90

Output Current lout (mA)

120

150

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- 8. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 9. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
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